

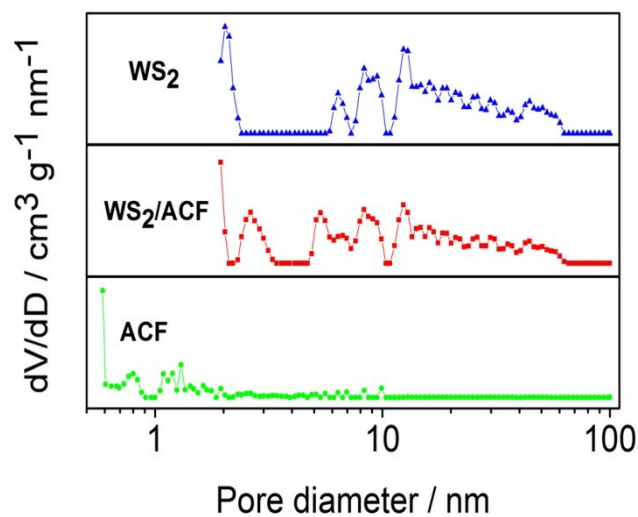
## Supporting information

### Immobilization of tungsten disulfide nanosheets on active carbon fiber as electrode materials for high performance quasi-solid-state asymmetric supercapacitors

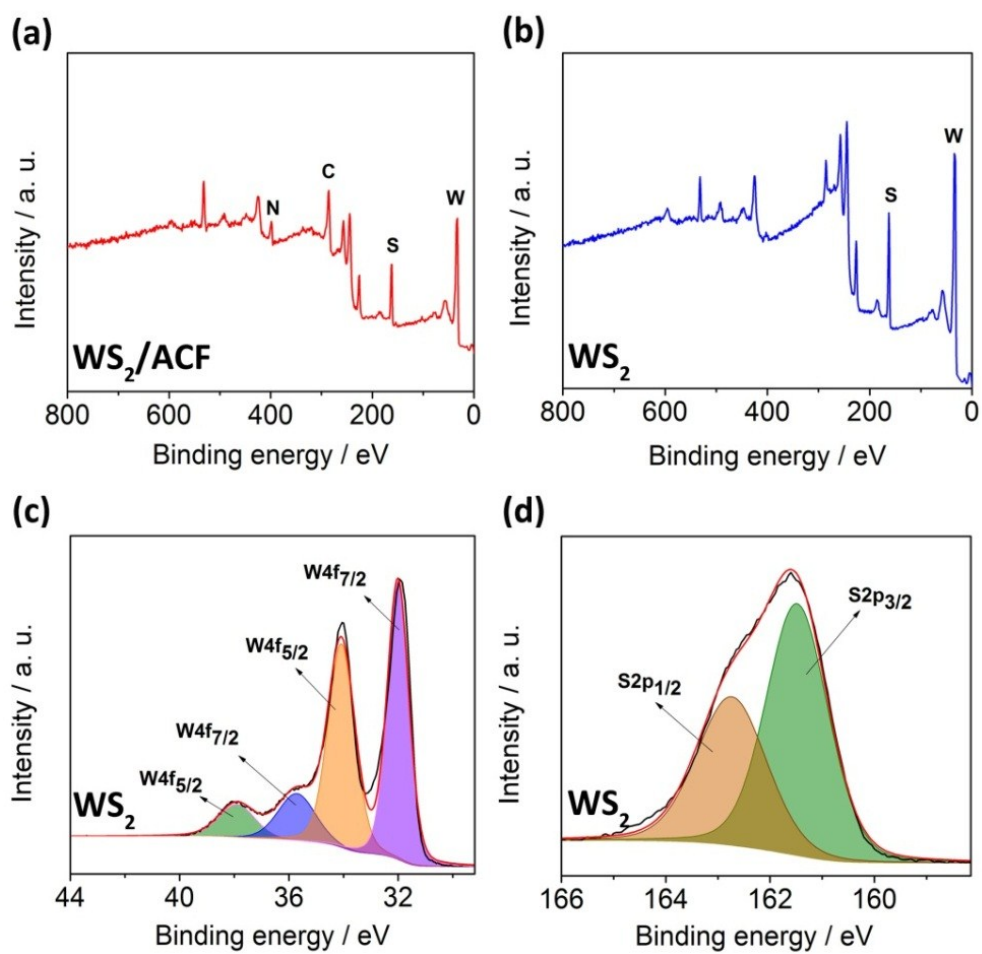
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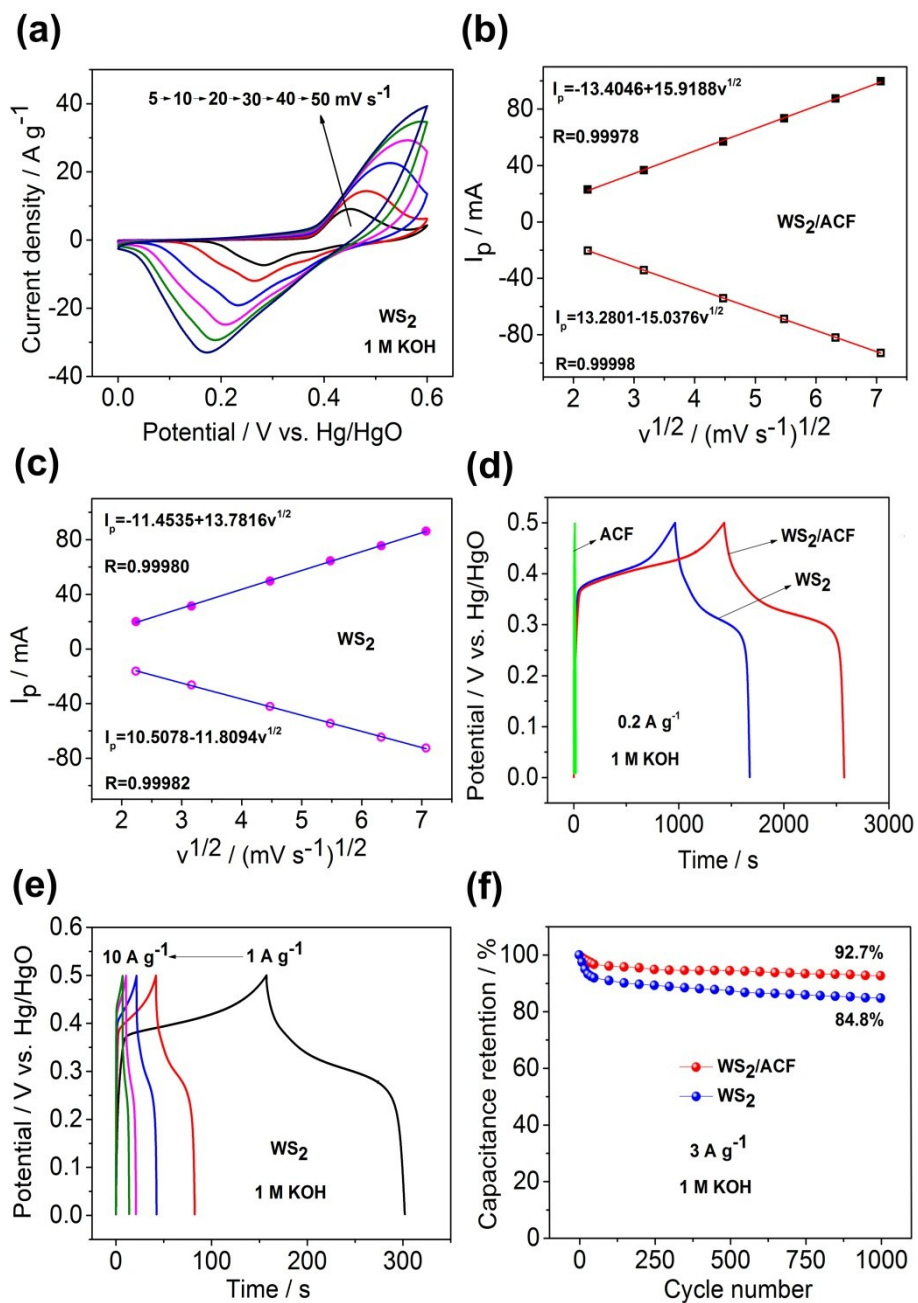
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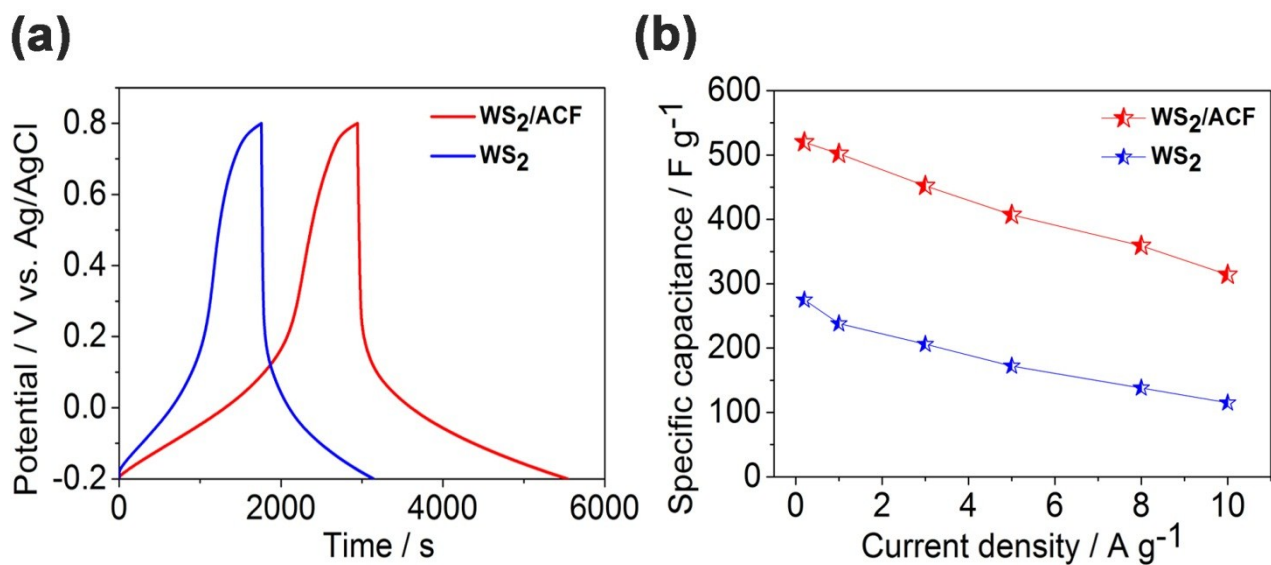
**Fig. S1** Pore size distribution of pure ACF, WS<sub>2</sub> and WS<sub>2</sub>/ACF calculated from the absorption-desorption isotherm using density functional theory (DFT) method.



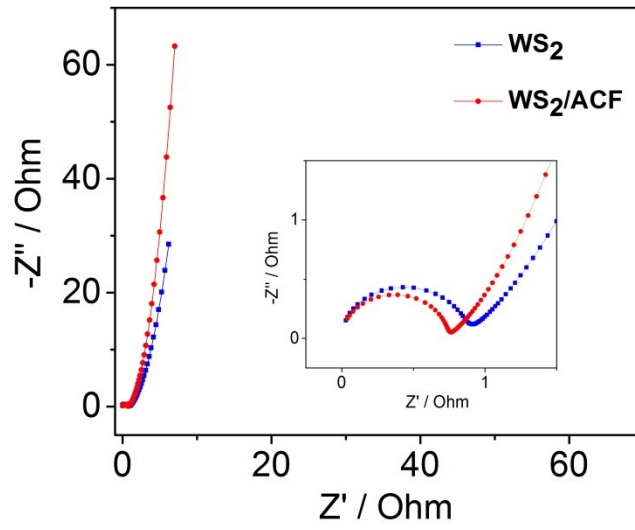
**Fig. S2** XPS spectra of WS<sub>2</sub>/ACF (a) and pure WS<sub>2</sub> (b). High resolution XPS spectra of W4f (c) and S2p (d) for pure WS<sub>2</sub>.



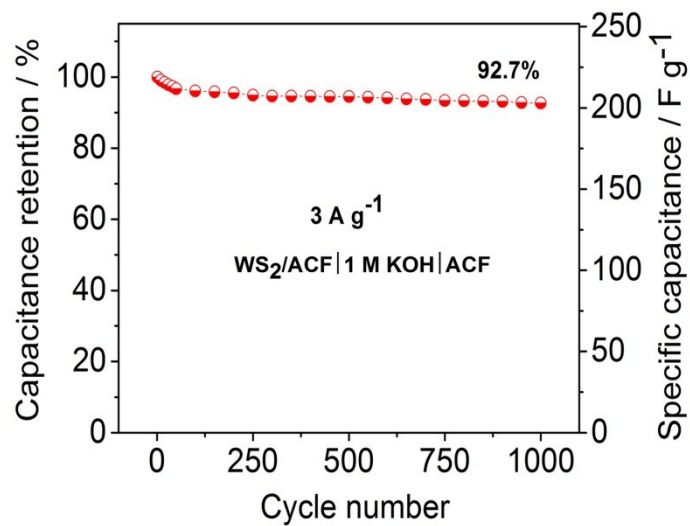
**Fig. S3** CV curves of pure  $\text{WS}_2$  at different scan rates (a), plots of the current at different scan rates (b and c), galvanostatic charge-discharge curves of ACF,  $\text{WS}_2$ , and  $\text{WS}_2/\text{ACF}$  at  $0.2 \text{ A g}^{-1}$  (d), galvanostatic charge-discharge curves of  $\text{WS}_2$  at different current densities (e), cyclic performance of  $\text{WS}_2$  and  $\text{WS}_2/\text{ACF}$  at  $3 \text{ A g}^{-1}$  in  $1 \text{ mol L}^{-1}$  KOH (f).



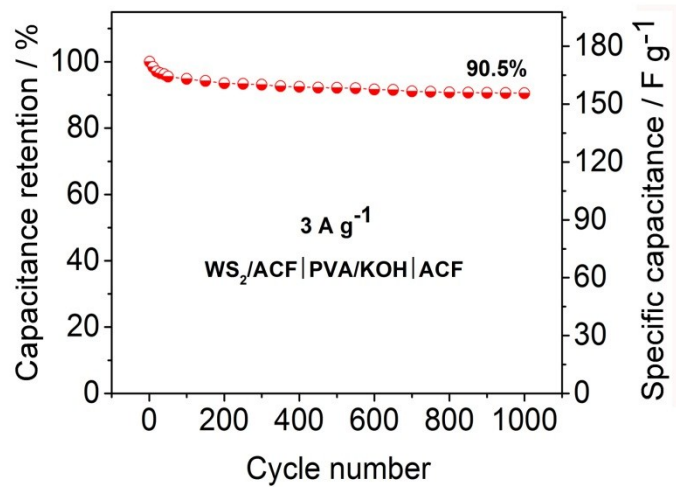
**Fig. S4** (c) galvanostatic charge-discharge curves of pure WS<sub>2</sub> and WS<sub>2</sub>/ACF at 0.2 A g<sup>-1</sup>, (d) rate performance covers of pure WS<sub>2</sub> and WS<sub>2</sub>/ACF.



**Fig. S5** EIS curves of  $\text{WS}_2/\text{ACF}$  and  $\text{WS}_2$  in  $1 \text{ mol L}^{-1}$  KOH.



**Fig. S6** The capacity retention during galvanostatic charge-discharge cycling of the WS<sub>2</sub>/ACF//ACF at 3 A g<sup>-1</sup> in 1 mol L<sup>-1</sup> KOH.



**Fig. S7** The capacity retention during galvanostatic charge-discharge cycling of the WS<sub>2</sub>/ACF//ACF at 3 A g<sup>-1</sup> in PVA/KOH.

**Table S1** Specific capacitance of metal sulfide based composite

	Materials	Current density (A g <sup>-1</sup> )	Capacitance (F g <sup>-1</sup> )	Electrolyte	Reference
1	PPy/MoS <sub>2</sub>	1	553.7	1 mol L <sup>-1</sup> KCl	1
2	MoS <sub>2</sub> /graphene nanosheets	2	320	1 mol L <sup>-1</sup> Na <sub>2</sub> SO <sub>4</sub>	2
3	s-MoS <sub>2</sub> /carbon nanospheres	0.5	231	1 mol L <sup>-1</sup> Na <sub>2</sub> SO <sub>4</sub>	3
4	MoS <sub>2</sub> /N-doped graphene	0.25	245	1 mol L <sup>-1</sup> KOH	4
5	Porous tubular C/MoS <sub>2</sub>	1	210	3 mol L <sup>-1</sup> Na <sub>2</sub> SO <sub>4</sub>	5
6	3D graphene/MoS <sub>2</sub>	1	410	1 mol L <sup>-1</sup> Na <sub>2</sub> SO <sub>4</sub>	6
7	WS <sub>2</sub>	0.5	34	Phosphate buffer solution (pH 7.4)	7
8	WS <sub>2</sub> -PANI	0.2	382	2 mol L <sup>-1</sup> H <sub>2</sub> SO <sub>4</sub>	8
9	WS <sub>2</sub> /RGO	0.5	350	1 mol L <sup>-1</sup> H <sub>2</sub> SO <sub>4</sub>	9
10	WS <sub>2</sub> /ACF	1	502	1 mol L <sup>-1</sup> H <sub>2</sub> SO <sub>4</sub>	This work
11	WS <sub>2</sub> /ACF	1	600	1 mol L <sup>-1</sup> KOH	This work

## References

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